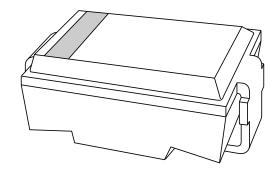
DISCRETE SEMICONDUCTORS

DATA SHEET



BYG60 series Fast soft-recovery controlled avalanche rectifiers

Preliminary specification
File under Discrete Semiconductors, SC01

1996 Jun 05





BYG60 series

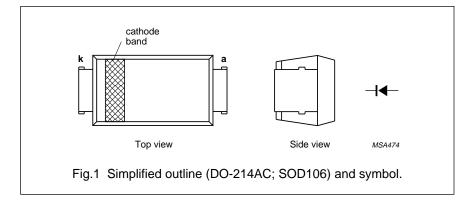
FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- UL 94V-O classified plastic package
- Shipped in 12 mm embossed tape.

DESCRIPTION

DO-214AC surface mountable package with glass passivated chip.

The well-defined void-free case is of a transfer-moulded thermo-setting plastic.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage				
	BYG60D		_	200	V
	BYG60G		_	400	V
	BYG60J		_	600	V
	BYG60K		_	800	V
	BYG60M		_	1000	V
V _R	continuous reverse voltage				
	BYG60D		_	200	V
	BYG60G		_	400	V
	BYG60J		_	600	V
	BYG60K		_	800	V
	BYG60M		_	1000	V
I _{F(AV)}	average forward current	averaged over any 20 ms period; T _{tp} = 100 °C; see Fig.2	_	1.90	А
		averaged over any 20 ms period; Al ₂ O ₃ PCB mounting (see Fig.7); T _{amb} = 60 °C; see Fig.3	_	0.90	A
		averaged over any 20 ms period; epoxy PCB mounting (see Fig.7); T _{amb} = 60 °C; see Fig.3	_	0.65	A
I _{FSM}	non-repetitive peak forward current	t = 10 ms half sine wave; $T_j = T_{j \text{ max}}$ prior to surge; $V_R = V_{RRMmax}$	_	25	A

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
E _{RSM}	non-repetitive peak reverse avalanche energy	L = 120 mH; $T_j = T_{j \text{ max}}$ prior to surge; inductive load switched off			
	BYG60D to J		_	10	mJ
	BYG60K and M		_	7	mJ
T _{stg}	storage temperature		-65	+175	°C
Tj	junction temperature	see Fig.4	-65	+175	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage	$I_F = 1 \text{ A}; T_j = T_{j \text{ max}}; \text{ see Fig.5}$	_	_	0.98	V
		I _F = 1 A; see Fig.5	_	_	1.20	V
V _{(BR)R}	reverse avalanche breakdown voltage	I _R = 0.1 mA				
	BYG60D		300	_	_	V
	BYG60G		500	_	_	V
	BYG60J		700	_	_	V
	BYG60K		900	_	_	V
	BYG60M		1100	_	_	V
I _R	reverse current	V _R = V _{RRMmax} ; see Fig.6	_	_	5	μΑ
		$V_R = V_{RRMmax}$; $T_j = 165 ^{\circ}C$; see Fig.6	_	_	100	μΑ
t _{rr}	reverse recovery time	when switched from I _F = 0.5 A to				
	BYG60D to J	$I_R = 1 \text{ A}$; measured at $I_R = 0.25 \text{ A}$;	_	_	250	ns
	BYG60K and M	see Fig.8	_	_	300	ns
C _d	diode capacitance	V _R = 0 V; f = 1 MHz				
	BYG60D to J		_	30	_	pF
	BYG60K and M		_	25	_	pF

THERMAL CHARACTERISTICS

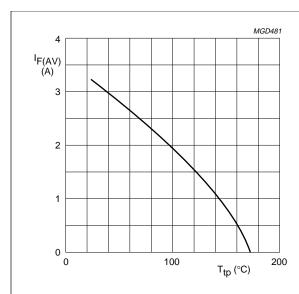
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		25	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	100	K/W
		note 2	150	K/W

Notes

- 1. Device mounted on Al_2O_3 printed-circuit board, 0.7 mm thick; thickness of copper \geq 35 μ m, see Fig.7.
- 2. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper \geq 40 μ m, see Fig.7. For more information please refer to the 'General Part of Handbook SC01'.

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GRAPHICAL DATA



 $V_R = V_{RRMmax}$; $\delta = 0.5$; a = 1.57.

Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).

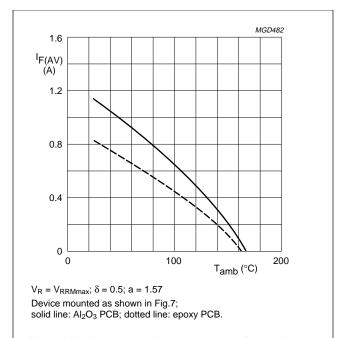
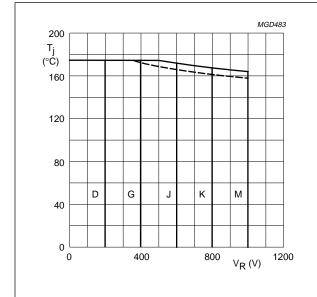


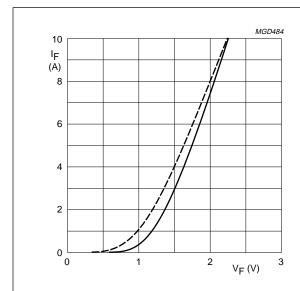
Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



Device mounted as shown in Fig.7 Solid line: Al₂O₃ PCB

Dotted line: epoxy PCB.

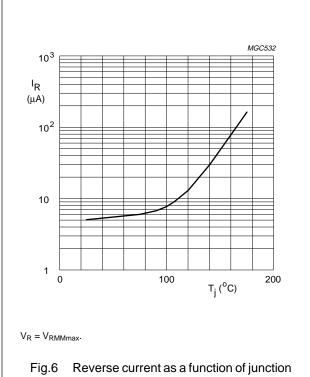
Fig.4 Maximum permissible junction temperature as a function of reverse voltage.



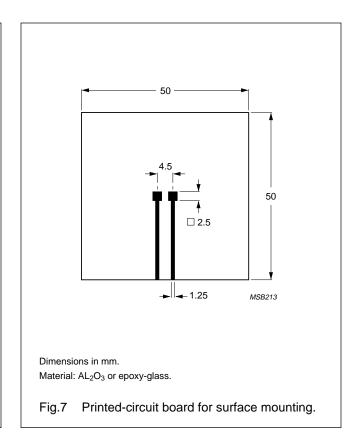
Solid line: $T_j = 25$ °C. Dotted line: $T_j = 175$ °C.

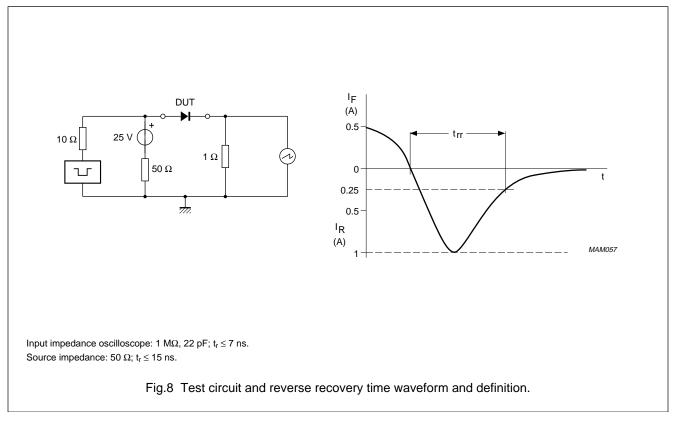
Fig.5 Forward current as a function of forward voltage; maximum values.

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temperature; maximum values.

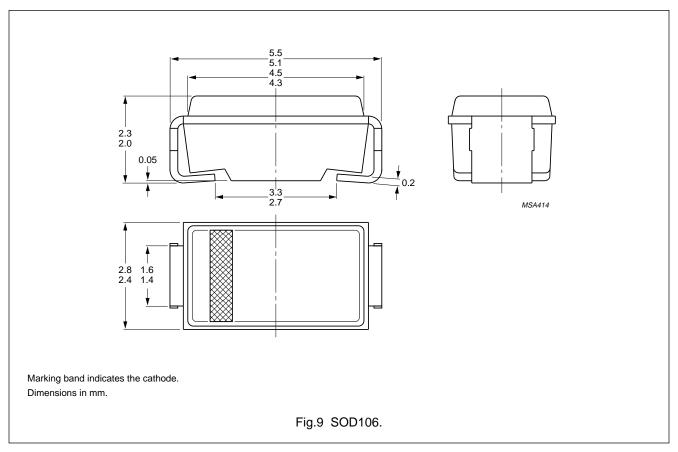




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PACKAGE OUTLINE



DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.